

Pb Free Product

NCE N-Channel Super Trench Power MOSFET

Description

The NCEP1505S uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

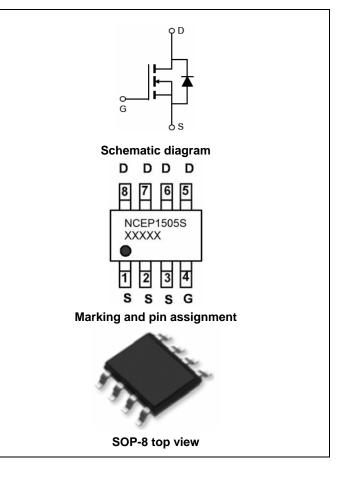
General Features

- V_{DS} =150V,I_D =5.1A $R_{DS(ON)} < 65m\Omega @ V_{GS}=10V$ (Typ: $55m\Omega$)
- Excellent gate charge x R_{DS(on)} product (FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature

Application

- DC/DC converters and Off-Line UPS
- High Voltage Synchronous Rectifier
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% ΔVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP1505S	NCEP1505S	SOP-8	Ø330mm	12mm	4000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	150	V
Gate-Source Voltage		V _{GS}	±20	V
Drain Current-Continuous		I _D	5.1	Α
Drain Current-Continuous(T _C =10	00℃)	I _D (100℃)	3.6	Α
Pulsed Drain Current(Note 1)		I _{DM}	20	Α
Single pulse avalanche energy (I	Note 5)	E _{AS}	60	mJ
$T_{\rm C} = 25 ^{\circ}{\rm C}$		D	5	W
Maximum Power Dissipation	T _A = 25 °C	$ P_{D}$	3	W
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55 To 150	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	$R_{\theta JA}$	41.7	°C/W
Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	25	C/ VV

NCEP1505S

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	150	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.5	3.3	4.5	V	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5.1A	-	55	65	mΩ	
Forward Transconductance	g FS	V_{DS} =5 V , I_D =5.1 A	-	12.5	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C _{lss}	V_{DS} =75 V , V_{GS} =0 V ,	-	550	730	PF	
Output Capacitance	C _{oss}	V _{DS} =75V,V _{GS} =0V, F=1.0MHz	-	62	80	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIHZ		2.5	4.5	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t _{d(on)}		-	7.5	14	nS	
Turn-on Rise Time	t _r	V_{DD} =75V, I_{D} =5.1A	-	1.4	8.5	nS	
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =10 V , R_{G} =3 Ω	-	12.5	21	nS	
Turn-Off Fall Time	t _f		-	2.5	8	nS	
Total Gate Charge	Q_g	\/ -75\/ -5 10	-	8.5	12	nC	
Gate-Source Charge	Q_{gs}	V_{DS} =75V, I_{D} =5.1A, V_{GS} =10V	-	2.8		nC	
Gate-Drain Charge	Q_{gd}	VGS-10V	-	1.9		nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =5.1A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	5.1	Α	
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	58	95	nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	69	110	nC	

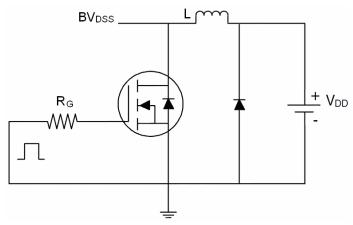
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. The value of R_{BJA} is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V $_{DD}$ =50 V,V $_{G}$ =10 V,L=0.5 mH,Rg=25 Ω

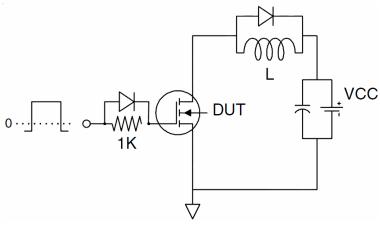


Test Circuit

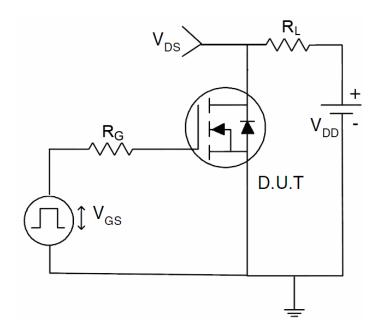
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

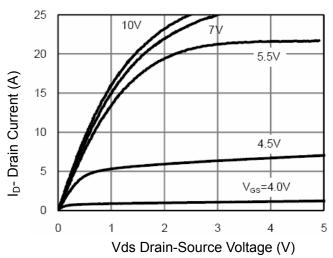


Figure 1 Output Characteristics

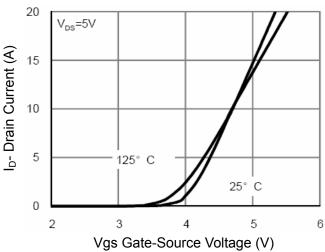


Figure 2 Transfer Characteristics

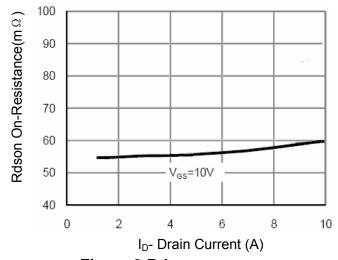


Figure 3 Rdson- Drain Current

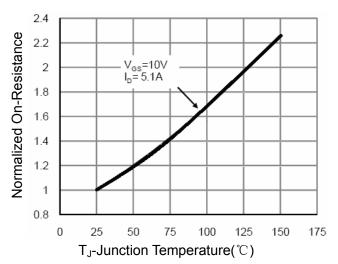


Figure 4 Rdson-JunctionTemperature

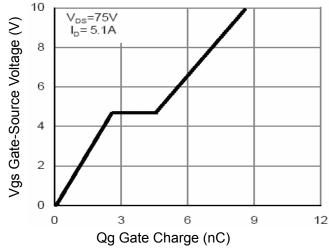


Figure 5 Gate Charge

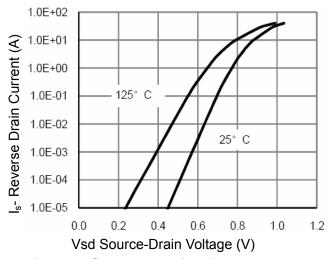


Figure 6 Source- Drain Diode Forward



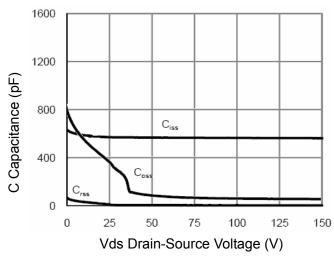


Figure 7 Capacitance vs Vds

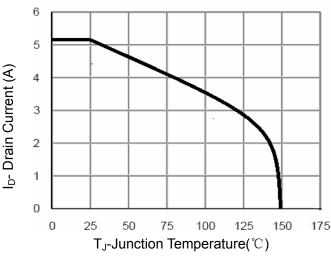


Figure 9 Current De-rating

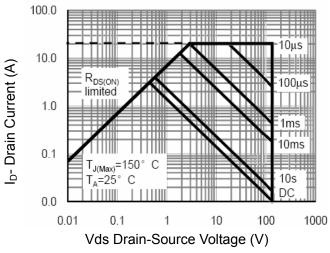


Figure 8 Safe Operation Area

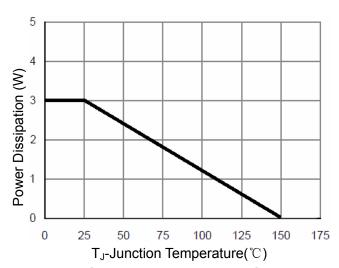


Figure 10 Power De-rating

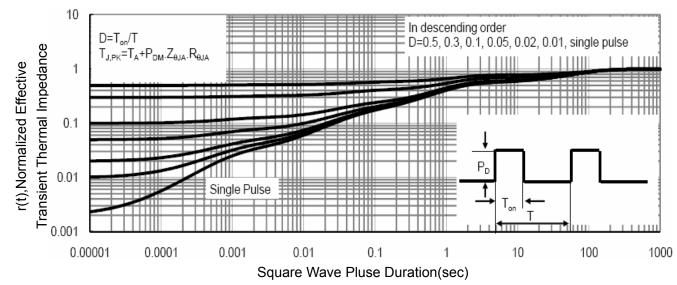
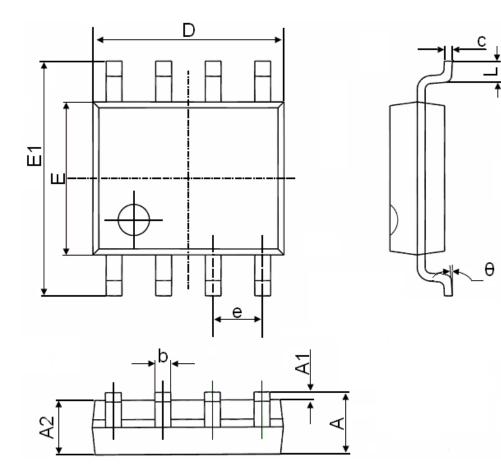


Figure 11 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



Cumbal	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



http://www.ncepower.com

NCEP1505S

Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.

单击下面可查看定价,库存,交付和生命周期等信息

>>NCEPOWER(无锡新洁能)